

Industry's first 1200 V SiC IPM CIPOS[™] Maxi IM828-series

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Global trends are driving demand for new power semiconductor solutions





Clean energy

Renewable energy sources like wind and sun are the vital part of new global energy mix



Energy efficiency

Reduction of energy consumed is needed, enabling systems that make the way we live and work greener



Electric mobility

Electrification of mobility is inevitable – in both, private and public transport segment





Silicon Carbide (SiC) can be an answer to these challenges

New requirements & challenges



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Functional integration on system level is mainstream – even up to highest power



System benefits translate to customer advantages IPMs improve time to market, performance and reliability

Broad Intelligent Power Module portfolio – serving power ranges from 20 W to 4 kW





Intelligent Power Module Portfolio



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Products		Key Features	Product Line				
DIP 36x23D	package	 Fully isolated Dual In-Line molded module with 1200 V CoolSiC[™] MOSFET Power capability over 8 kW 	Part No.	Package DIP 36x23D	Rds(on) 55 mΩ	Voltage Rating 1200 V	Ver. CoolSiC™ MOSFET
Constant of the second		 > Improved heat dissipation > Rugged 1200 V SOI gate driver technology (6ED) > Integrated bootstrap functionality > Over current shutdown > Independent temperature thermistor 	Topology: 3 phase inverter				
		Under-voltage lockout at all channels	Value Proposition				
Dimension		 Low side pins accessible for all phase current monitoring 	 Offer very low loss by using the advanced CooSiC[™] MOSFET technology High power density and high efficiency 				
[mm]	36 x 22.7 x 3.1 mm ³ with 24 pins	Application					
Configuration	3-phase inverter with open emitters	Commercial air conditioners	 High output power in one small package 				
Voltage Rating	1200 V	-Active filter (PFC)/compressor	> Provide	wide swite	hing spe	ed range	-
Rds(on)	$(I_D=20 \text{ A}, \text{ Vin}=5 \text{ V}, \text{T}_J < 25^{\circ}\text{C})$	 Industrial motor drives 	> Minimiz	e system s	ize and r	educe sy	stem costs
I _D DC drain current	20 A (T _c = 80°C, T _J < 150°C)	→ Pumps	Fast tim	e to marke	et		

IM828-MCC shows superior thermal performance compared to Reference A

Test conditions	DUT	Measured value			Simulated data		
		Ta [°C]	Tc [°C]	Tca [°C]	Tj max. [°C]	Loss(INV)	
Case 1	IM828-XCC	26.1	54.4	28.3	83.0	77.92	
(5 kHz, 25 Apeak, MI=0.58)	Reference A	26.6	68.2	41.6	84.1	132.14	
Case 2	IM828-XCC	25.9	41.6	15.7	58.6	44.02	
(30 kHz, 7 Apeak, MI=0.64)	Reference A	26.5	92.0	65.5	99.7	168.91	

Comments

Reference A is 1200 V 50 A IPM based on Si-IGBT technology

 V_{DC} =600 V, V_{DD} =15 V, R_{shunt} =10 m Ω , F_{O} =60 Hz, PF=0.99, T_{dead} =0.5 µs (SiC-MOSFET) / 3 µs (Si-IGBT)







IM828-XCC SiC IPM gives an excellent value to fit for various applications



Key Features	Key Benefits	Value	To fit for			
3 phase inverter topology with smallest compact molded package, up to 8 kW	Minimized PCB size	Reduced system costs	Servo Dynamic and heavy load High power disspation requirement			
power rating	 Easy PCB footprint design 	Fast time to market	 > High efficiency requirement > High switching frequency 			
Embedded single 1200 V	> Less peripheral components		PFC (Active filter) for pump or HVAC			
SOI gate driver technology	Wide switching speed range	Wide range of application	Ar/Ar/Ar/Ar/Ar/Ar/Ar/Ar/Ar/Ar/Ar/Ar/Ar/A			
 > Built-in bootstrap > Over current shutdown > Under-voltage lockout 	 Maintain stability against transient 	High efficiency	 Improve system stable capability High power factor requiremen High efficiency requirement 			
 All of 6 switches turn off during protection Enable pin Excellent thermal 	 Lower switching losses 	High power density	High switching frequency requirement CAC compressor			
 performance with DCB substrate Independent thermistor 	 Monitoring system thermal status 	High output power	 System simplify and easy design High power rating requirement 			

IM828-XCC in compact package with high output power and low heat dissipation for servo drive applications







Comments

Miniaturization of servo drive

- High power requirement for dynamic load condition
- High power density and good thermal performance requirement based on the compact mechanical structure with heavy load
- High efficiency and high switching frequency requirement

CIPOS[™] Maxi offers the highest power density compact solution with SiC IPM

- High power rating with excellent protection functions
- > Small and compact design with good thermal performance
- High efficiency and wide range for switching frequency
- Highest power density of system

IM828-XCC with excellent performance for high frequency and low heat dissipation for PFC applications





High Power and High Performance IM828-XCC with Wide Speed Range for HVAC Application





Comments

Miniaturized high performance HVAC

- Require harmonic current suppression capability
 - IEC/EU 61000-3-2 standard requirement
- Require high performance and stable capability
- Minimized system cost such as size and weight

CIPOS[™] Maxi offers complete IPM revolutionary solution: ①+②+③

- Excellent high frequency capability to achieve high power factor for suppress harmonic current to meet standard
- High output power can be generated at low frequency to drive compressor
- High efficency and highest power density to privode system stable capability
- Compact system design to reduce 70% inductor core size/PCB size and 75% weight for saving huge space

EVAL-M1-IM828-A MADK evaluation board: IM828-XCC SiC IPM performance for 8 kW motor drive







Thermal image of evaluation board: Output power 8.9 kW



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IM828 SiC IPM: next level of performance

- Infineon has a long and successful history with SiC diodes and power switches
- SiC represents a strong technology option for applications needing higher performance and efficiency
- IM828 full SiC intelligent power module is the latest and greatest addition to the portfolio of Infineon's CoolSiC products:
 - High power density and low losses enable system cost savings
 - High switching frequency enables high performance for systems requiring high load dynamics
 - High switching frequency enables significant system cost reductions in active filter applications
- Full industrial qualification, high reliability and robustness





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